

- optimum if

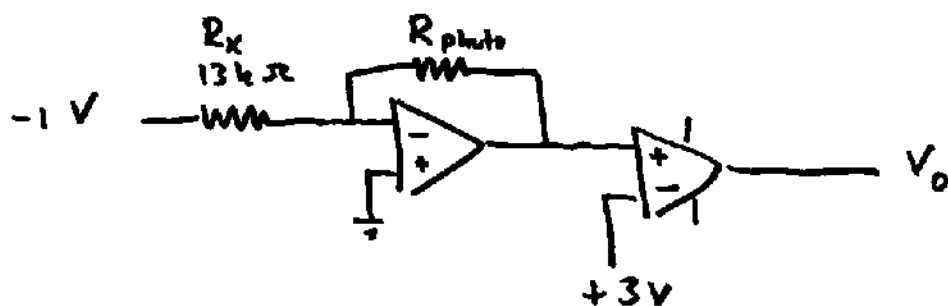
$$h\nu = E_g, \quad \lambda = \frac{c}{\nu} \quad \left(\begin{array}{l} \text{note:} \\ [m] = \frac{[m/s]}{[1/s]} \end{array} \right)$$

$$\lambda_{opt} \approx \frac{hc}{E_g} \quad \text{note: } 1 \text{ eV} = 1.6 \times 10^{-19} \text{ J}, \quad \frac{hc}{e} = 1.24 \times 10^{-6} \frac{[m]}{[eV]}$$

material	band gap	λ_{opt}	
Si	1.12 eV	1107 nm	IR
Ge	0.66 eV	1879 nm	FIR
GaAs	1.42 eV	873 nm	red
C	5.47 eV	227 nm	UV

$$R(t) = \underbrace{R_f}_{100 \text{ k}\Omega} + (\underbrace{R_i - R_f}_{-70 \text{ k}\Omega}) \exp\left(-\underbrace{t/\tau}_{72 \text{ ms}}\right)$$

$$R(10 \text{ ms}) = 39.077 \text{ k}\Omega$$

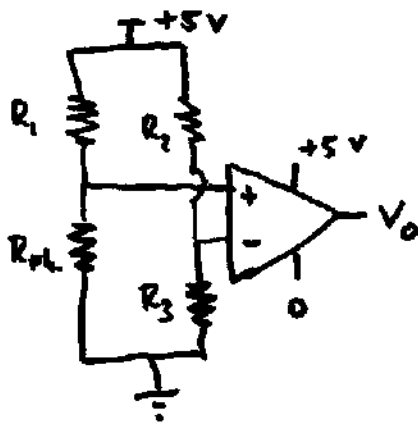


$$-1 \text{ V} \cdot \left(-\frac{R_{photo}}{R_x} \right) = +3 \text{ V}$$

$$R_{photo} = 39.077 \text{ k}\Omega \rightarrow R_x = 13 \text{ k}\Omega$$

(solution Curtis Johnson, p. 247)

Alternative circuit (1 power supply):



$$V_n = 3 \text{ V}$$

$$R_3 = 3 \text{ k}\Omega, \quad R_2 = 2 \text{ k}\Omega$$

$$R_1 : \quad V_D = \frac{R_{pk}}{R_{pk} + R_1} \times 5 \Rightarrow$$

$$3 = \frac{39.077}{39.077 + R_1} \times 5 \Rightarrow R_1 = 26.05 \text{ k}\Omega$$